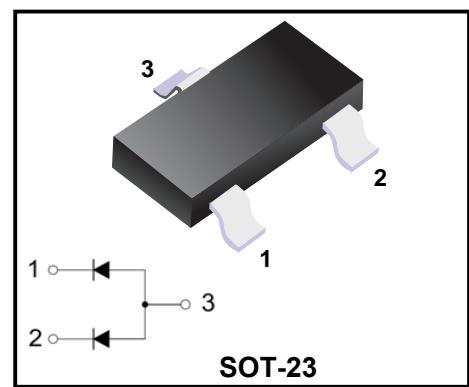


FEATURES

- ◆ Fast Switching Speed
- ◆ For General Purpose Switching Applications
- ◆ High Conductance



Marking Code	
BAW156	JZ

Absolute Maximum Ratings (Ta =25 °C)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V _{RRM}	85	V
Continuous Reverse Voltage	V _R	75	V
Continuous Forward Current (Double Diode Loaded)	I _F	125	mA
Continuous Forward Current (Single Diode Loaded)	I _F	215	mA
Repetitive Peak Forward Current	I _{FRM}	500	mA
Non-repetitive Peak Forward Surge Current at t = 1 s at t = 1 ms at t = 1 µs	I _{FSM}	0.5 1 4.5	A
Power Dissipation	P _{tot}	350	mW
Junction Temperature	T _j	150	°C
Storage Temperature Range	T _{stg}	- 65 to + 150	°C

Characteristics at Ta =25 °C

Parameter	Symbol	Max.	Unit
Forward Voltage at I _F = 1 mA at I _F = 10 mA at I _F = 50 mA at I _F = 150 mA	V _F	0.715 0.855 1 1.25	V
Reverse Current at V _R = 25 V at V _R = 75 V at V _R = 25 V, T _j = 150 °C at V _R = 75 V, T _j = 150 °C	I _R	30 1 30 50	nA µA µA µA
Diode Capacitance at V _R = 0 , f = 1 MHz	C _d	1.5	pF
Reverse Recovery Time at I _F = I _R = 10 mA, I _R = 1 mA, R _L = 100 Ω	t _{rr}	4	ns

Ratings and Characteristic Curves

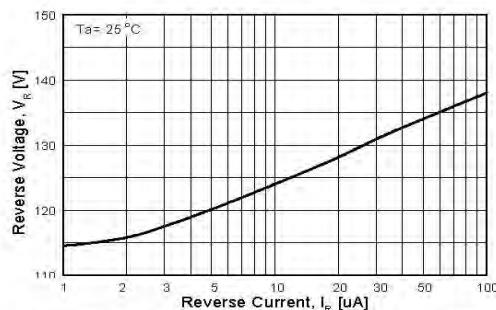


Figure 1. Reverse Voltage vs Reverse Current
BV - 1.0 to 100uA

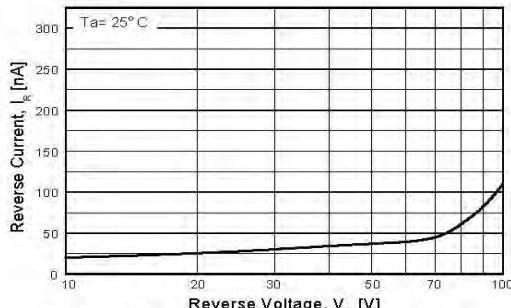


Figure 2. Reverse Current vs Reverse Voltage
IR - 10 to 100 V

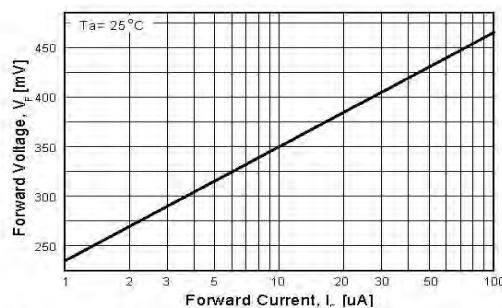


Figure 3. Forward Voltage vs Forward Current
VF - 1.0 to 100 uA

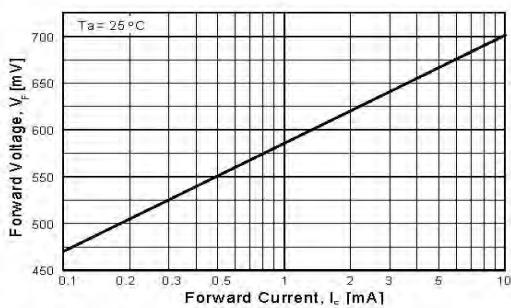


Figure 4. Forward Voltage vs Forward Current
VF - 0.1 to 10 mA

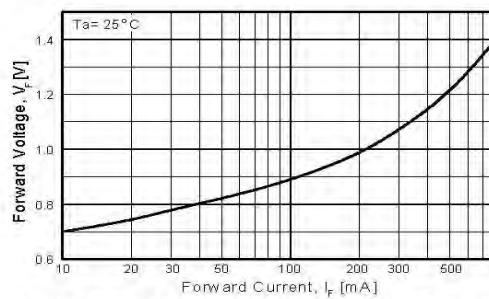


Figure 5. Forward Voltage vs Forward Current
VF - 10 - 800 mA

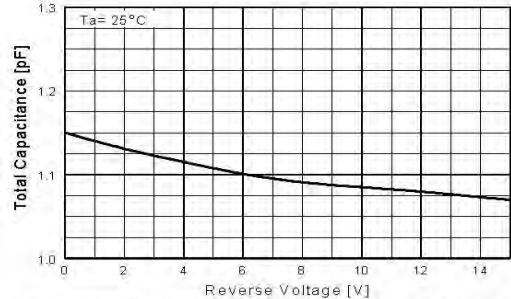


Figure 6. Total Capacitance vs Reverse Voltage

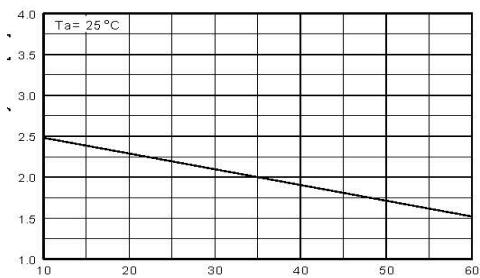


Figure 7. Reverse Recovery Time
vs Reverse Current
TRR - IR 10 mA vs 60 mA

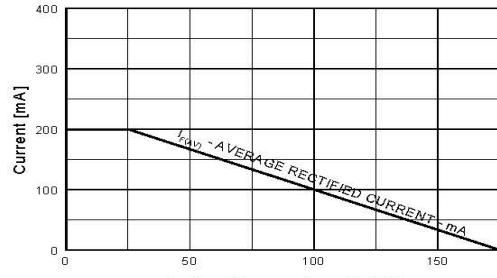


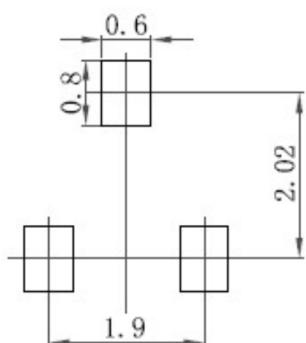
Figure 8. Average Rectified Current ($I_{F(AV)}$)
versus Ambient Temperature (T_A)

Ordering information

Package	Packing Description	Base Quantity	Packing Quantity
SOT-23	Tape/Reel,7"reel	3000pcs/Reel	24000PCS/Box 120000PCS/Carton

Package Dimensions
SOT-23

Dim.	Millimeter (mm)		mil	
	Min.	Max.	Min.	Max.
A	0.9	1.15	35	45
A1	0.1		3.9	
bp	0.38	0.48	15	19
C	0.09	0.15	3.54	5.9
D	2.8	3.0	110	118
E	1.2	1.4	47	55
E	1.9		75	
E1	0.95		37	
HE	2.1	2.55	83	100
Lp	0.15	0.45	5.9	18
Q	0.45	0.55	18	22
v	0.2		7.9	
W	0.1		4	

The recommended mounting pad size


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